

# SN54HCT126, SN74HCT126 QUADRUPLE BUS BUFFER GATES WITH 3-STATE OUTPUTS

SCLS070A – NOVEMBER 1988 – REVISED NOVEMBER 1990

- High-Current 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Inputs are TTL-Voltage Compatible
- Package Options Include “Small-Outline” Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

## description

These bus buffers feature independent line drivers with three-state outputs. Each output is disabled when the associated OE is low.

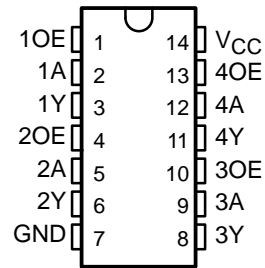
The SN54HCT126 is characterized for operation over the full military temperature range of  $-55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ . The SN74HCT126 is characterized for operation from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

FUNCTION TABLE

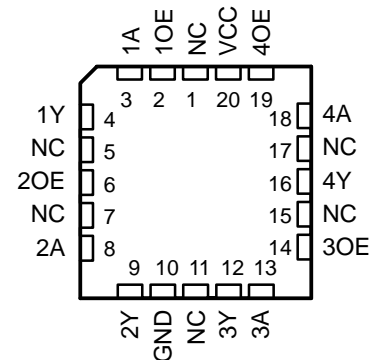
INPUTS		OUTPUT
OE	A	Y
H	H	H
H	L	L
L	X	Z

H = high level, L = low level,  
X = irrelevant

SN54HCT126 ... J PACKAGE  
SN74HCT126 ... D OR N PACKAGE  
(TOP VIEW)

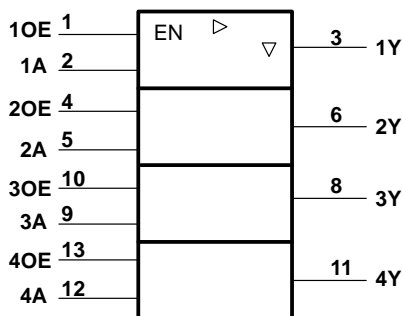


SN54HCT126 ... FK PACKAGE  
(TOP VIEW)



NC – No internal connection

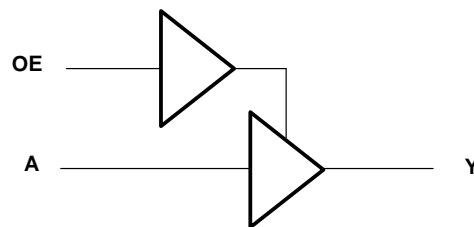
## logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for D, J, and N packages.

## logic diagram (each buffer) (positive logic)



# SN54HCT126, SN74HCT126

## QUADRUPLE BUS BUFFER GATES

### WITH 3-STATE OUTPUTS

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#### absolute maximum ratings over operating free-air temperature range †

Supply voltage range, $V_{CC}$	– 0.5 V to 7 V
Input clamp current, $I_{IK}$ ( $V_I < 0$ or $V_I > V_{CC}$ )	$\pm 20$ mA
Output clamp current, $I_{OK}$ ( $V_O < 0$ or $V_O > V_{CC}$ )	$\pm 20$ mA
Continuous output current, $I_O$ ( $V_O = 0$ to $V_{CC}$ )	$\pm 35$ mA
Continuous current through $V_{CC}$ or GND pins	$\pm 70$ mA
Lead temperature 1,6 mm (1/16 in) from case for 60 s: FK or J package	300°C
Lead temperature 1,6 mm (1/16 in) from case for 10 s: DW or N package	260°C
Storage temperature range	– 65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### recommended operating conditions

			SN54HCT126			SN74HCT126			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	
$V_{CC}$	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
$V_{IH}$	High-level input voltage	$V_{CC} = 4.5$ V to 5.5 V	2			2			V
$V_{IL}$	Low-level input voltage	$V_{CC} = 4.5$ V to 5.5 V	0		0.8	0		0.8	V
$V_I$	Input voltage		0		$V_{CC}$	0		$V_{CC}$	V
$V_O$	Output voltage		0		$V_{CC}$	0		$V_{CC}$	V
$t_t$	Input transition (rise and fall) times		0		500	0		500	ns
$T_A$	Operating free-air temperature		–55		125	–40		85	°C

#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{CC}$	$T_A = 25^\circ\text{C}$			SN54HCT126		SN74HCT126		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
$V_{OH}$	$V_I = V_{IH}$ or $V_{IL}$ , $I_{OH} = -20$ $\mu\text{A}$	4.5 V	4.4	4.499		4.4		4.4		V
	$V_I = V_{IH}$ or $V_{IL}$ , $I_{OH} = -6$ mA	4.5 V	3.98	4.30		3.7		3.84		
$V_{OL}$	$V_I = V_{IH}$ or $V_{IL}$ , $I_{OL} = 20$ $\mu\text{A}$	4.5 V		0.001	0.1		0.1		0.1	V
	$V_I = V_{IH}$ or $V_{IL}$ , $I_{OL} = 6$ mA	4.5 V		0.17	0.26		0.4		0.33	
$I_I$	$V_I = V_{CC}$ or 0	5.5 V		$\pm 0.1$	$\pm 100$		$\pm 1000$		$\pm 1000$	nA
$I_{OZ}$	$V_O = V_{CC}$ or 0, $V_I = V_{IH}$ or $V_{IL}$	5.5 V		$\pm 0.01$	$\pm 0.5$		$\pm 10$		$\pm 5$	$\mu\text{A}$
$I_{CC}$	$V_I = V_{CC}$ or 0, $I_O = 0$	5.5 V			8		160		80	$\mu\text{A}$
$\Delta I_{CC}^\ddagger$	One input at 0.5 V or 2.4 V, Other inputs at 0 V or $V_{CC}$	5.5 V		1.4	2.4		3		2.9	mA
$C_i$		4.5 to 5.5 V		3	10				10	pF
							10 §			

‡ This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or  $V_{CC}$ .

§ On products compliant to MIL-STD-883, Class B, this parameter is not production-tested.



**SN54HCT126, SN74HCT126**  
**QUADRUPLE BUS BUFFER GATES**  
**WITH 3-STATE OUTPUTS**

SCLS070A – NOVEMBER 1988 – REVISED NOVEMBER 1990

**switching characteristics over recommended operating free-air temperature range,  $C_L = 50$  pF (unless otherwise noted) (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}$	$T_A = 25^\circ\text{C}$			SN54HCT126		SN74HCT126		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
$t_{pd}$	A	Y	4.5 V		15	26		33		33	ns
			5.5 V		12	23		35		30	
$t_{en}$	OE	Y	4.5 V		19	26		39		33	ns
			5.5 V		15	23		35		30	
$t_{dis}$	OE	Y	4.5 V		18	26		39		33	ns
			5.5 V		15	23		35		30	
$t_t$		Any	4.5 V		8	15		22		19	ns
			5.5 V		7	14		21		17	

**switching characteristics over recommended operating free-air temperature range,  $C_L = 150$  pF (unless otherwise noted) (see Figure 1)**

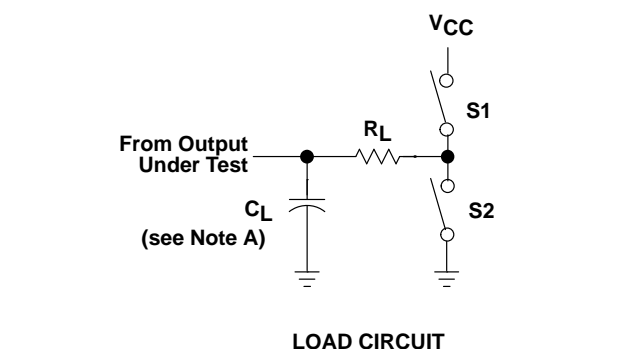
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}$	$T_A = 25^\circ\text{C}$			SN54HCT126		SN74HCT126		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
$t_{pd}$	A	Y	4.5 V		21	36		58		46	ns
			5.5 V		17	32		48		42	
$t_{en}$	OE	Y	4.5 V		25	36		58		46	ns
			5.5 V		21	32		48		42	
$t_t$		Any	4.5 V		17	42		63		53	ns
			5.5 V		14	38		57		48	

$C_{pd}$	Power dissipation capacitance	No load, $T_A = 25^\circ\text{C}$	35 pF typ
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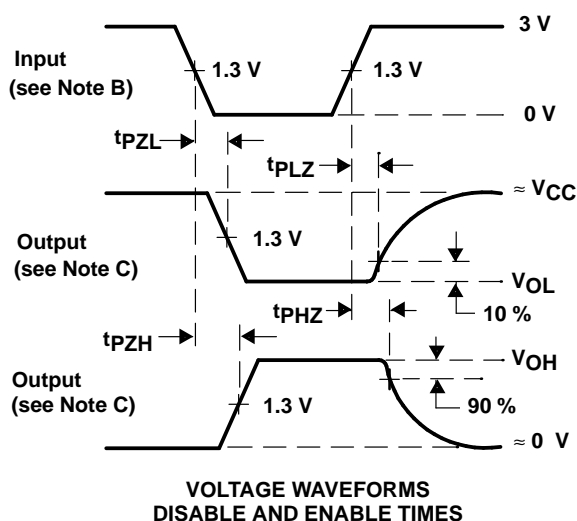
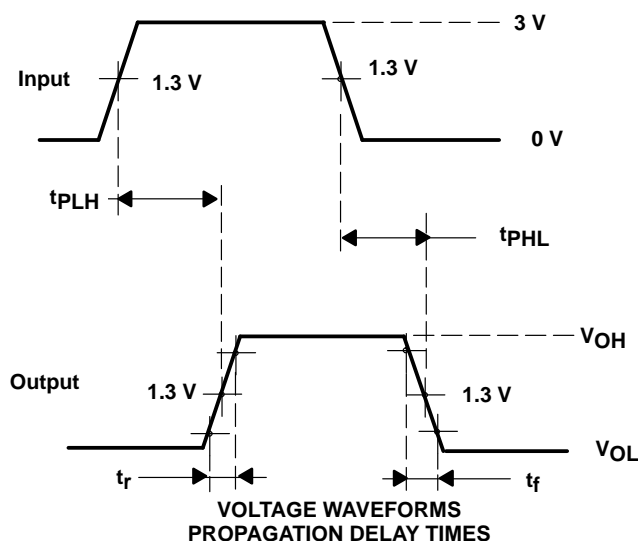
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## PARAMETER MEASUREMENT INFORMATION



PARAMETER	$R_L$	$C_L$	S1	S2
$t_{en}$	1 k $\Omega$	50 pF or 150 pF	Open	Closed
			Closed	Open
$t_{dis}$	1 k $\Omega$	50 pF	Open	Closed
			Closed	Open
$t_{pd}$ or $t_t$	–	50 pF or 150 pF	Open	Open



NOTES: A.  $C_L$  includes probe and jig capacitance.

B. All input pulses are supplied by generators having the following characteristics:

PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq 6$  ns,  $t_f \leq 6$  ns.

C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.

Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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